

P-CHANNEL MOS FIELD EFFECT TRANSISTOR
 FOR SWITCHING

DESCRIPTION

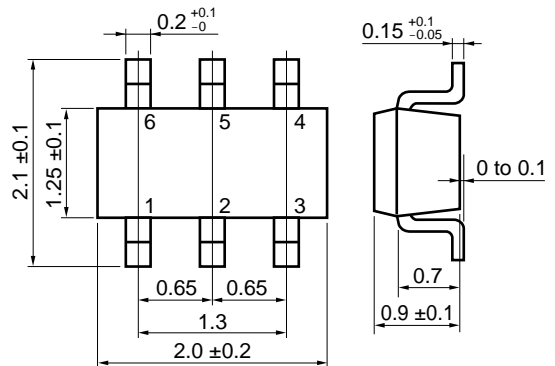
The μ PA678TB is a switching device, which can be driven directly by a 2.5 V power source.

The μ PA678TB features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 2.5 V drive available
- Low on-state resistance
 $R_{DS(on)1} = 1.45 \Omega$ MAX. ($V_{GS} = -4.5$ V, $I_D = -0.20$ A)
 $R_{DS(on)2} = 1.55 \Omega$ MAX. ($V_{GS} = -4.0$ V, $I_D = -0.20$ A)
 $R_{DS(on)3} = 2.98 \Omega$ MAX. ($V_{GS} = -2.5$ V, $I_D = -0.15$ A)
- Two MOS FET circuits in same size package as SC-70

PACKAGE DRAWING (Unit: mm)



ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA678TB	SC-88 (SSP)

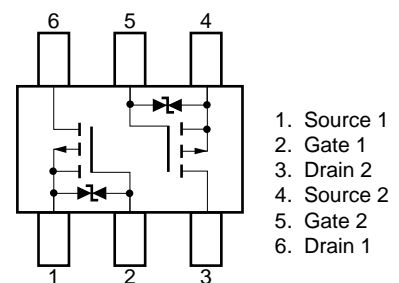
Marking: XA

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0$ V)	V_{DSS}	-20	V
Gate to Source Voltage ($V_{DS} = 0$ V)	V_{GSS}	∓ 12	V
Drain Current (DC)	$I_{D(DC)}$	∓ 0.25	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	∓ 1.00	A
Total Power Dissipation (2 units) ^{Note2}	P_T	0.2	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

- Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$
 2. Mounted on FR-4 board of $2500 \text{ mm}^2 \times 1.1 \text{ mm}$

PIN CONNECTION (Top View)



1. Source 1
2. Gate 1
3. Drain 2
4. Source 2
5. Gate 2
6. Drain 1

Caution This product is electrostatic-sensitive device due to low ESD capability and should be handled with caution for electrostatic discharge.
 $V_{ESD} = \pm 100$ V TYP. ($C = 200$ pF, $R = 0 \Omega$, Single pulse)

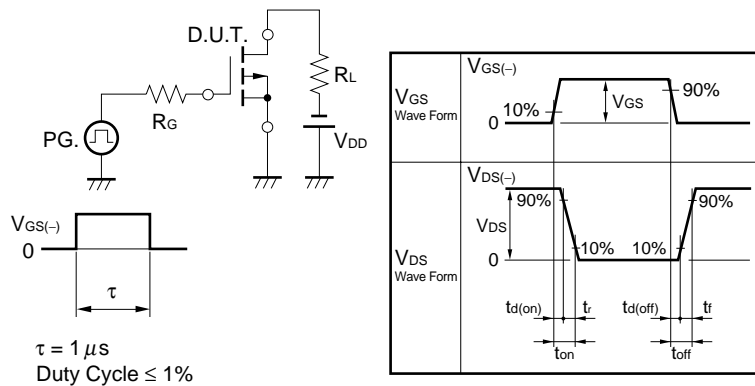
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

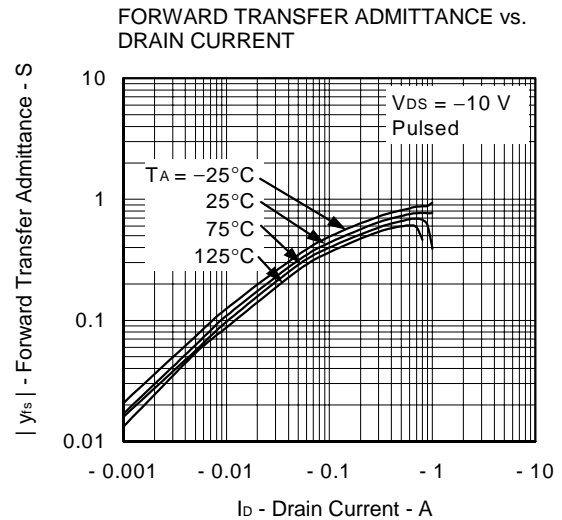
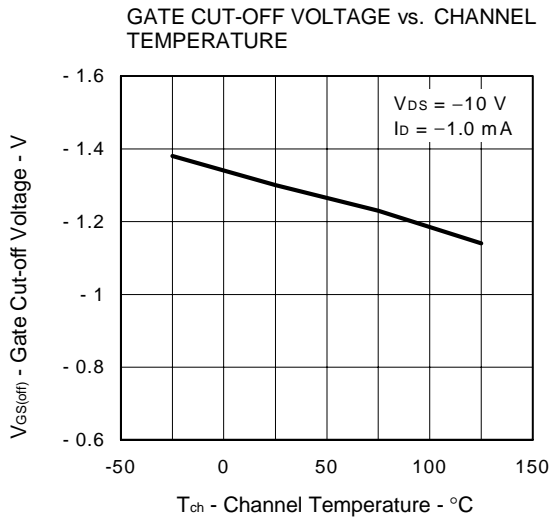
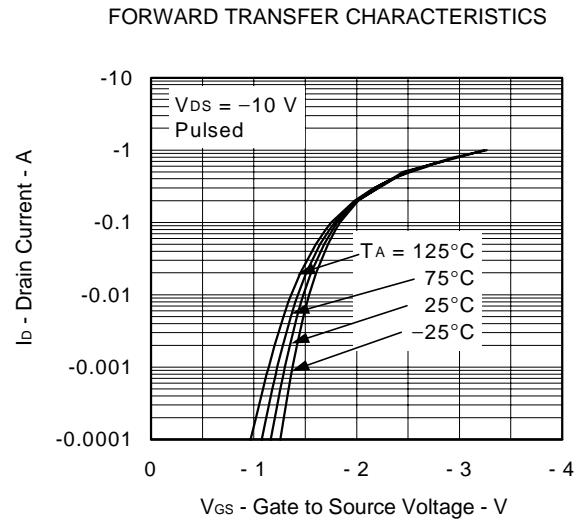
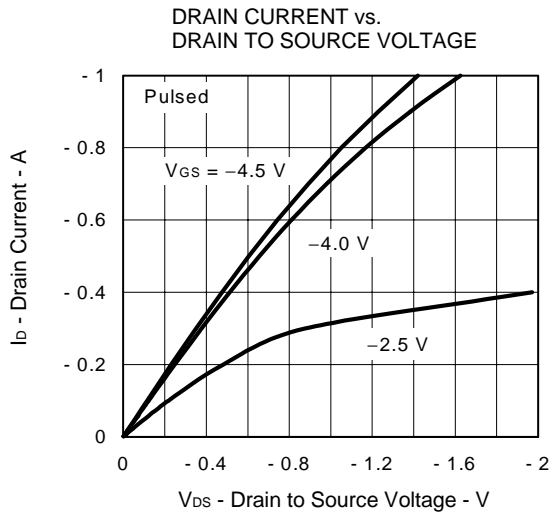
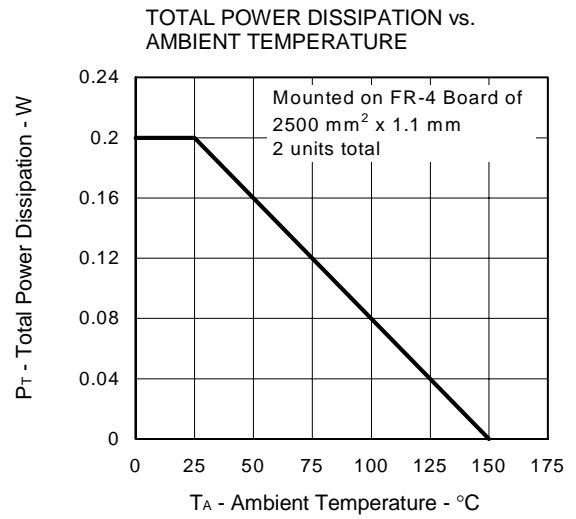
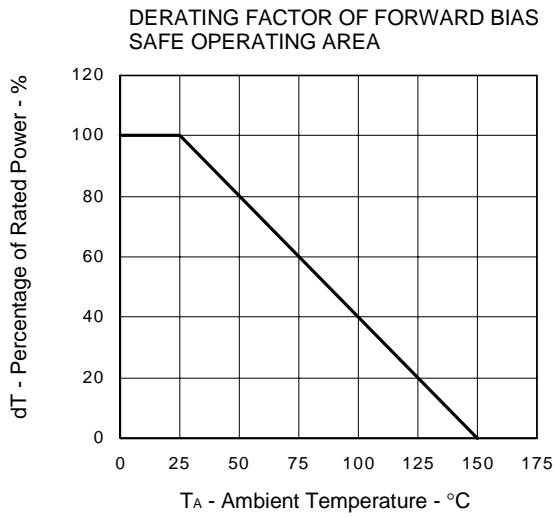
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -20.0 V, V _{GS} = 0 V			-1.0	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±12.0 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage ^{Note}	V _{GS(off)}	V _{DS} = -10.0 V, I _D = -1.0 mA	-0.8	-1.3	-1.8	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = -10.0 V, I _D = -0.20 A	0.2	0.6		S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)1}	V _{GS} = -4.5 V, I _D = -0.20 A		1.17	1.45	Ω
	R _{DS(on)2}	V _{GS} = -4.0 V, I _D = -0.20 A		1.25	1.55	Ω
	R _{DS(on)3}	V _{GS} = -2.5 V, I _D = -0.15 A		2.25	2.98	Ω
Input Capacitance	C _{iss}	V _{DS} = -10.0 V		29		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		15		pF
Reverse Transfer Capacitance	C _{rss}	f = 1.0 MHz		3		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = -10.0 V, I _D = -0.20 A		23		ns
Rise Time	t _r	V _{GS} = -4.0 V		39		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		50		ns
Fall Time	t _f			33		ns
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 0.25 A, V _{GS} = 0 V		0.88		V

Note Pulsed: PW ≤ 350 μs, Duty cycle ≤ 2%

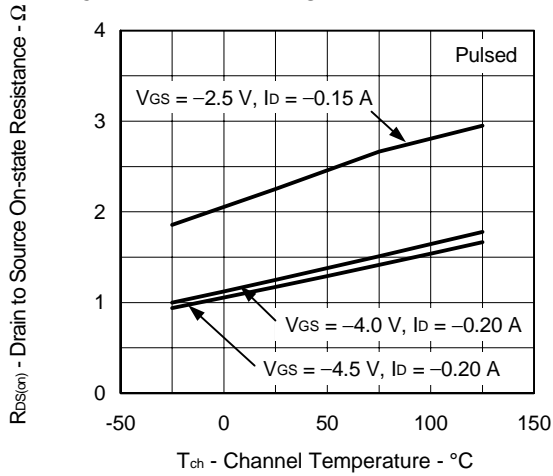
TEST CIRCUIT SWITCHING TIME



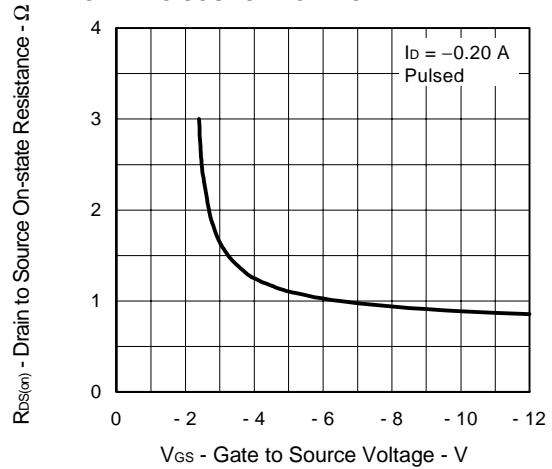
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



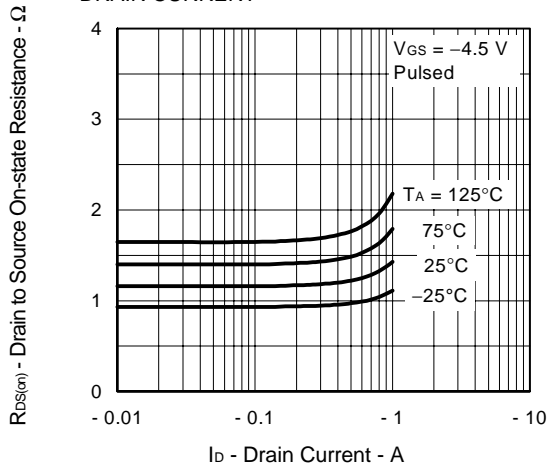
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



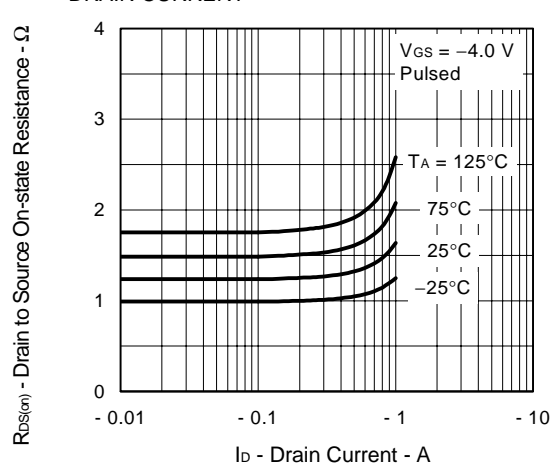
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



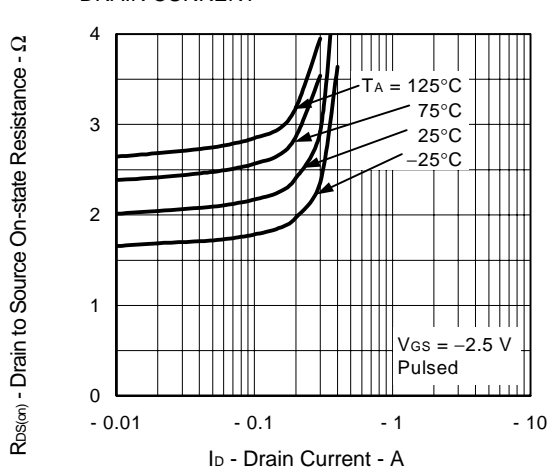
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



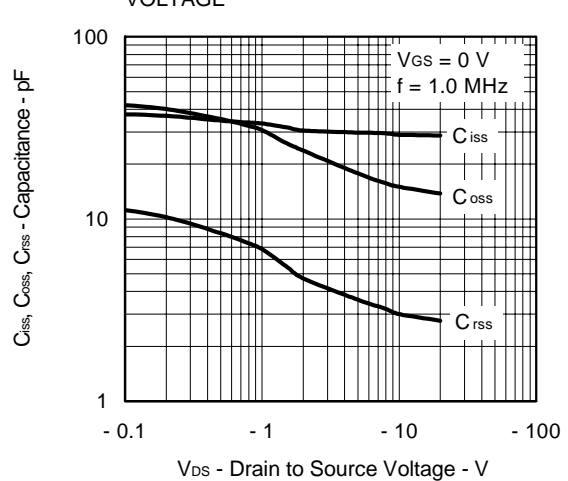
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



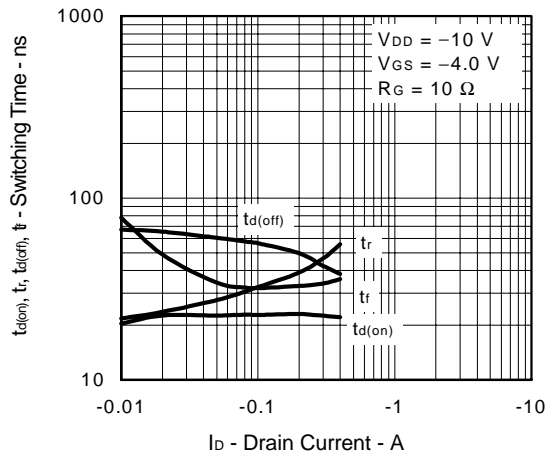
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



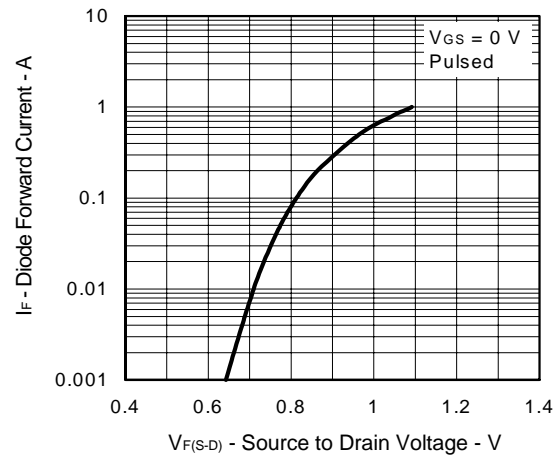
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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